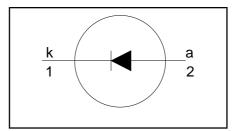
Rectifier diodes ultrafast

BYV29-600

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 600V$$
 $V_F \le 1.03 V$
 $I_{F(AV)} = 9 A$
 $t_{rr} \le 60 \text{ ns}$

GENERAL DESCRIPTION

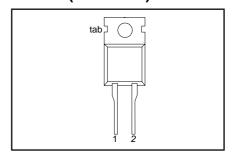
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV29-600 is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

DESCRIPTION		
cathode		
anode		
cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM} V _{RWM} V _R	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage		-	600 600 600	>>>
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 120 ^{\circ}\text{C}$	-	9	Α
I _{FRM}	Repetitive peak forward current	$t = 25 \mu s; δ = 0.5;$ $T_{mb} \le 120 °C$	-	18	Α
I _{FSM}	Non-repetitive peak forward current.	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	- -	70 77	A A
$egin{array}{c} T_{stg} \ T_{i} \end{array}$	Storage temperature Operating junction temperature	V _{RRM(max)}	-40 -	150 150	°C C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to		-	-	2.5	K/W
R _{th j-a}	mounting base Thermal resistance junction to ambient	in free air.	-	60	-	K/W

¹ Neglecting switching and reverse current losses.

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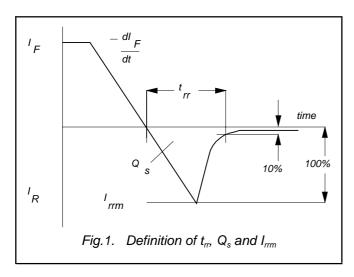
ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.90	1.03	V
		$I_F = 8 \text{ A}$	-	1.05	1.25	V
		$I_{\rm F} = 20 \text{A}$	-	1.30	1.45	V
l _R	Reverse current	$V_R = V_{RRM}$	-	2.0	50	μΑ
		$V_{R} = V_{RRM}$; $T_{i} = 100 ^{\circ}C$	-	0.1	0.35	mΑ
Q_s	Reverse recovery charge	$V_R = V_{RRM}$; $T_j = 100$ °C $I_F = 2$ A to $V_R \ge 30$ V;	-	40	70	nC
		$dI_{F}/dt = 20 A/\mu s$				
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	50	60	ns
		$dI_F/dt = 100 \dot{A}/\mu s$				
I _{rrm}	Peak reverse recovery current	$I_{F} = 10 \text{ A to V}_{R} \ge 30 \text{ V};$ $dI_{F}/dt = 50 \text{ A/}\mu\text{s}; T_{I} = 100^{\circ}\text{C}$	-	3.0	5.5	Α
		$dI_{F}/dt = 50 \text{ A/}\mu\text{s}; T_{i} = 100^{\circ}\text{C}$				
V_{fr}	Forward recovery voltage	$I_F = 10 \text{ A}$; $dI_F/dt = 10 \text{ A}/\mu\text{s}$	-	3.2	-	V

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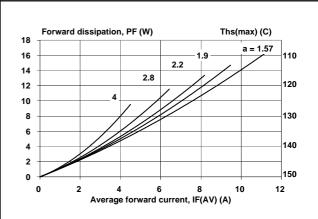
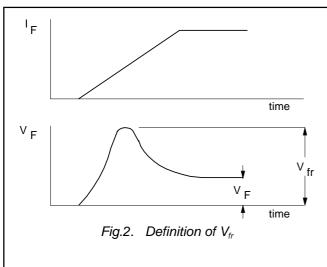
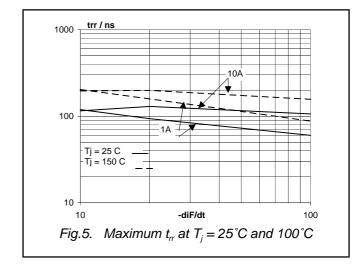
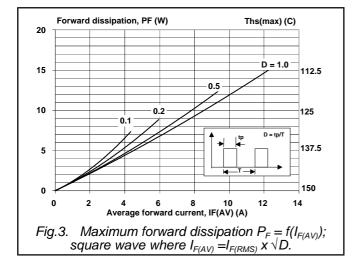
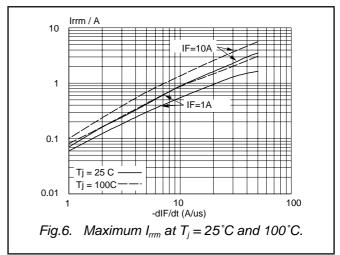


Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor $= I_{F(RMS)} / I_{F(AV)}$.





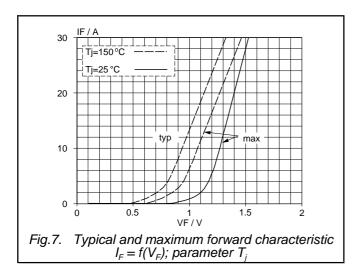


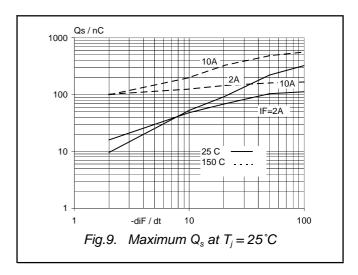


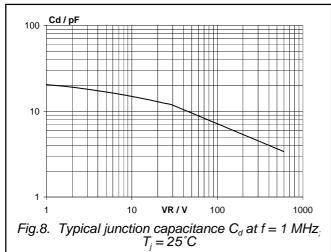
Philips Semiconductors Product specification

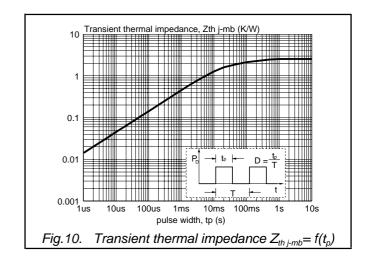
Rectifier diodes ultrafast

BYV29-600





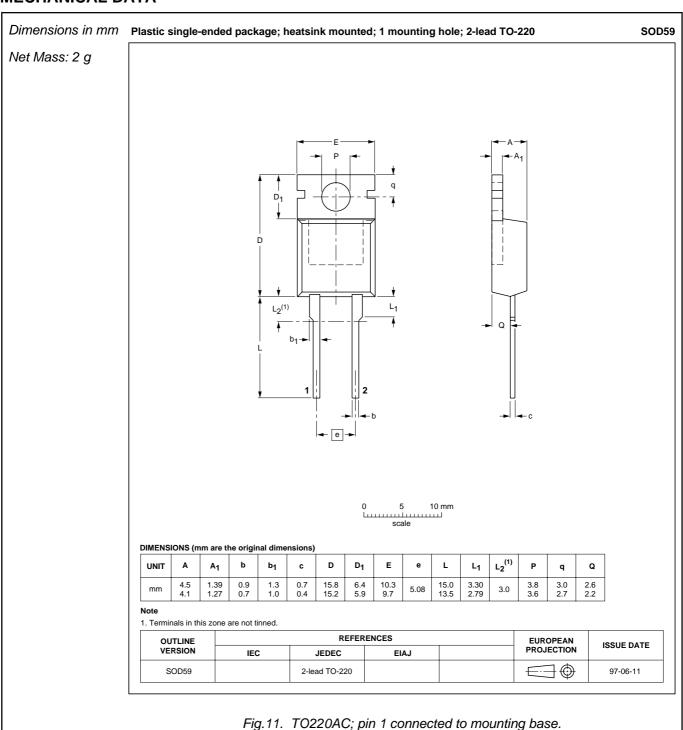




Rectifier diodes ultrafast

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MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes ultrafast

BYV29-600

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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